

**PATENT APPLICATION**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re application of

Docket No: Q76117

KIYOKU, Hiroyuki, et al.

This is a Divisional Application of  
Appln. No.: 10/261,487

Confirmation No.: Unknown

Prior Group Art Unit: 2822

Filed: June 23, 2003

Prior Examiner: Stephen D. Meier

For: NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR  
SUBSTRATE, AND NITRIDE SEMICONDUCTOR DEVICE

**PRELIMINARY AMENDMENT**

**MAIL STOP NON-FEE AMENDMENT**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Prior to examination, please amend the above-identified application as follows:

**IN THE SPECIFICATION:**

**Before the first line of the specification, please insert the following new paragraph:**

This is a divisional of Application No. 10/261,487 filed October 2, 2002, now pending,  
which is a divisional of Application No. 09/986,332 filed November 8, 2001, now pending,  
which is a Continuation of application Serial No. 09/603,437 filed June 23, 2000, now  
abandoned, which is a Division of application Serial No. 09/202,141 filed December 9, 1998,  
now U.S. Patent 6,153,010, which is a 35 U.S.C. § 371 of PCT/JP98/01640 filed April 9, 1998.